

Device Modeling Report

COMPONENTS: MOSFET (Professional Model)
PART NUMBER: 2SK3062
MANUFACTURER: NEC Corporation
REMARK: Body Diode (Professional Model) /
ESD Protection Diode



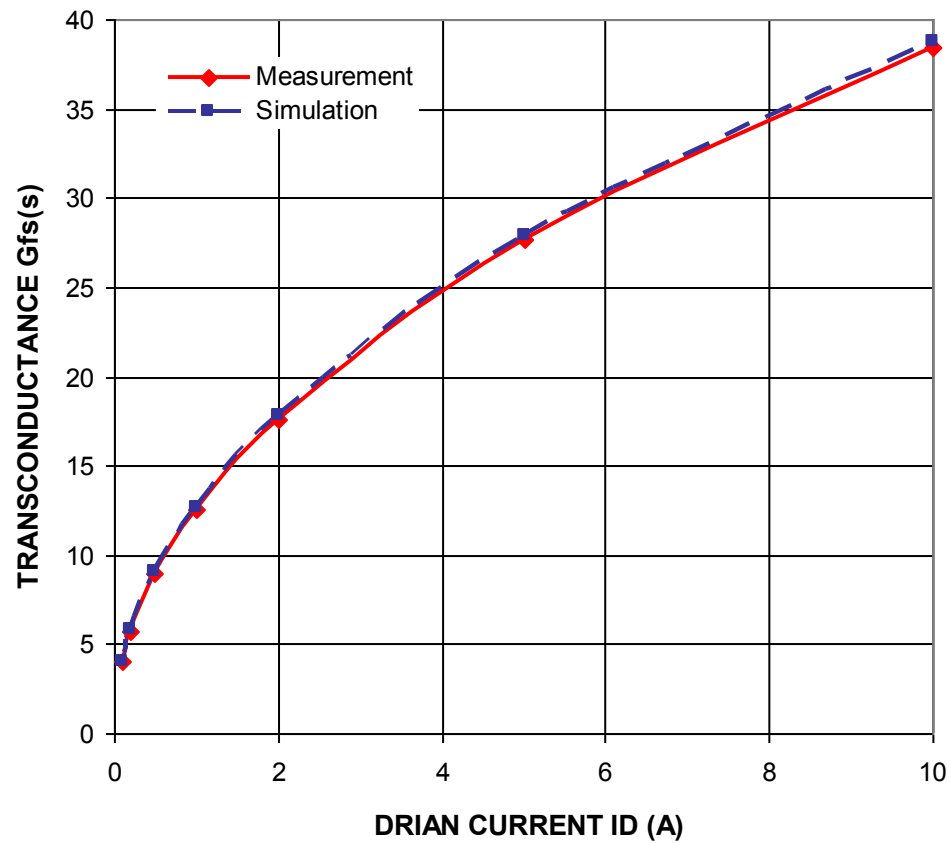
Bee Technologies Inc.

MOSFET MODEL

PSpice model parameter	Model description
LEVEL	
L	Channel Length
W	Channel Width
KP	Transconductance
RS	Source Ohmic Resistance
RD	Ohmic Drain Resistance
VTO	Zero-bias Threshold Voltage
RDS	Drain-Source Shunt Resistance
TOX	Gate Oxide Thickness
CGSO	Zero-bias Gate-Source Capacitance
CGDO	Zero-bias Gate-Drain Capacitance
CBD	Zero-bias Bulk-Drain Junction Capacitance
MJ	Bulk Junction Grading Coefficient
PB	Bulk Junction Potential
FC	Bulk Junction Forward-bias Capacitance Coefficient
RG	Gate Ohmic Resistance
IS	Bulk Junction Saturation Current
N	Bulk Junction Emission Coefficient
RB	Bulk Series Resistance
PHI	Surface Inversion Potential
GAMMA	Body-effect Parameter
DELTA	Width effect on Threshold Voltage
ETA	Static Feedback on Threshold Voltage
THETA	Modility Modulation
KAPPA	Saturation Field Factor
VMAX	Maximum Drift Velocity of Carriers
XJ	Metallurgical Junction Depth
UO	Surface Mobility

Transconductance Characteristics

Circuit Simulation Result

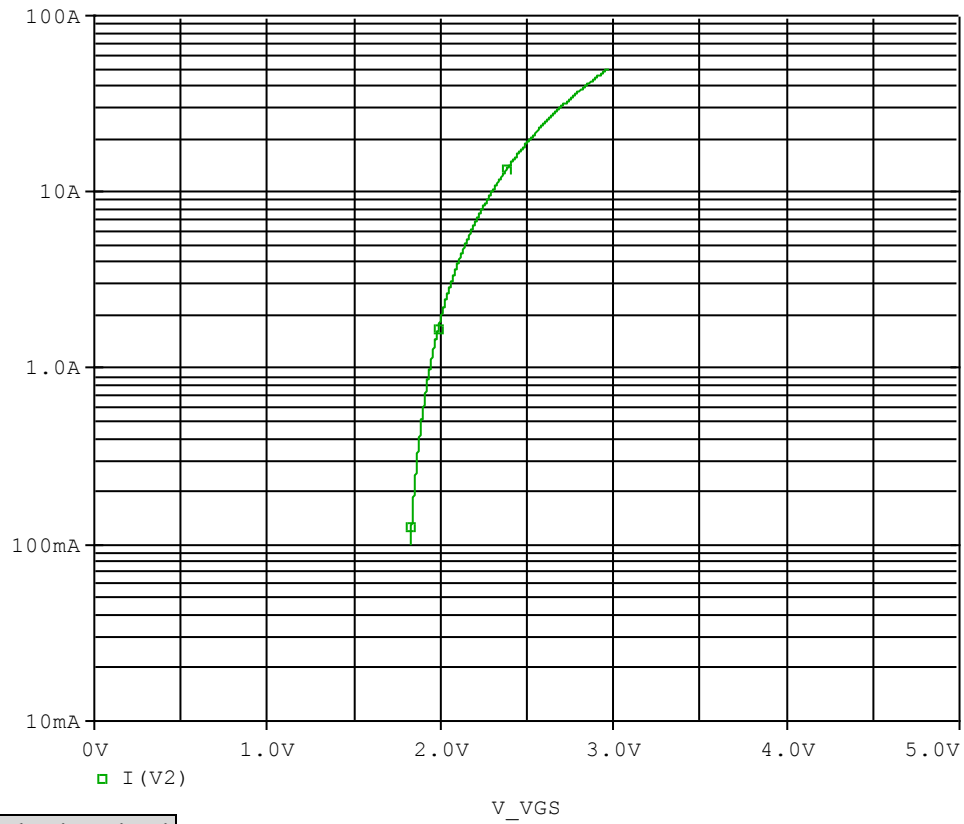


Comparison table

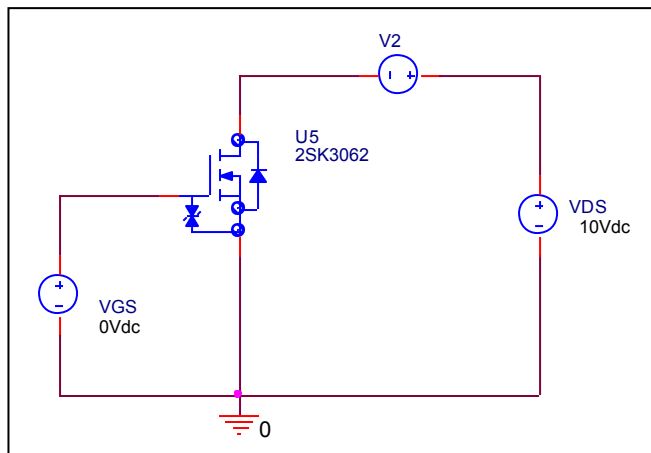
Id(A)	gfs(s)		Error(%)
	Measurement	Simulation	
0.1	4.000	4.089	2.222
0.2	5.714	5.854	2.450
0.5	8.929	9.070	1.584
1	12.500	12.705	1.640
2	17.544	17.830	1.631
5	27.624	27.888	0.955
10	38.462	38.756	0.766

Vgs-Id Characteristics

Circuit Simulation Result

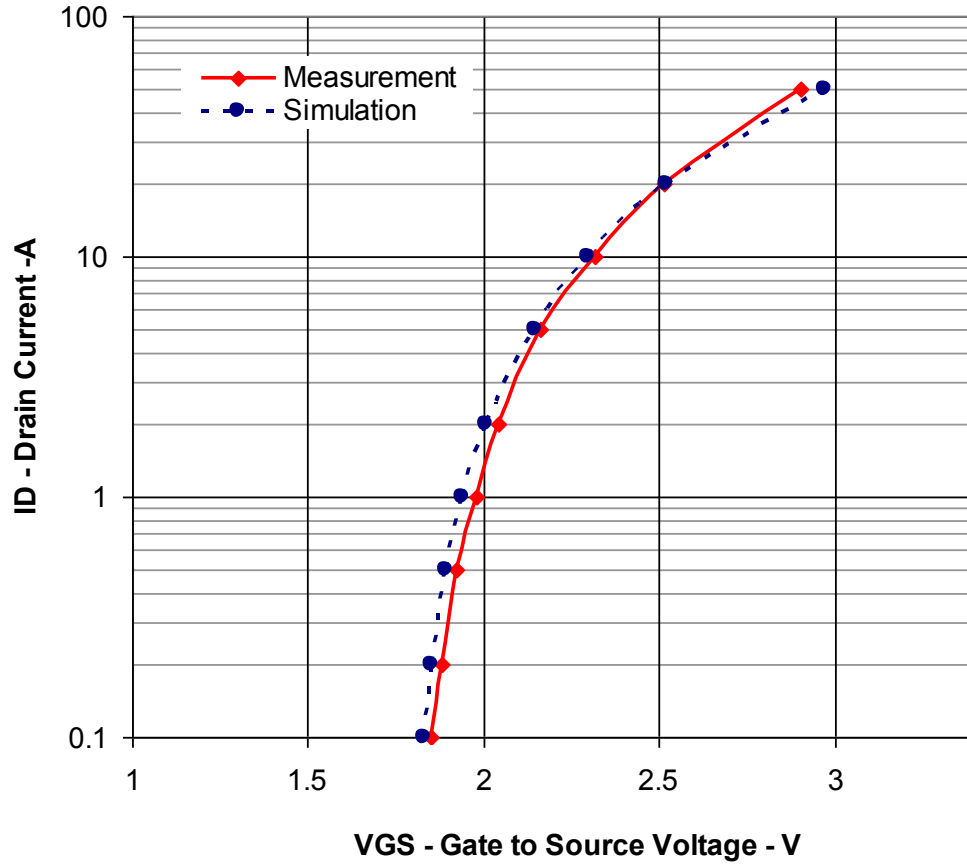


Evaluation circuit



Comparison Graph

Circuit Simulation Result

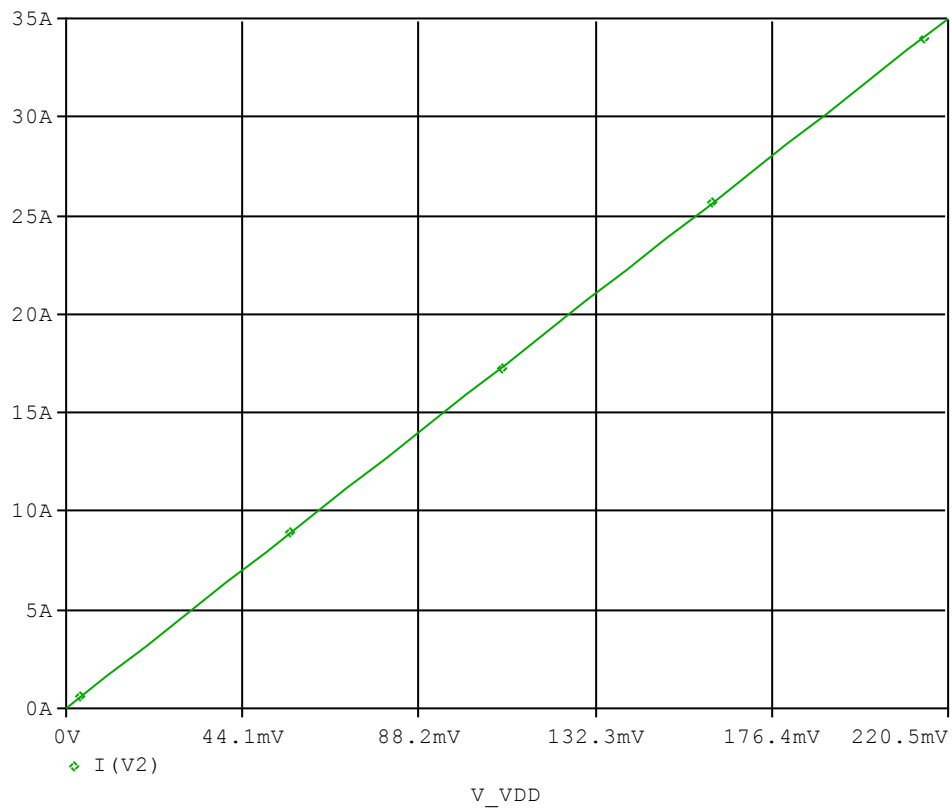


Comparison table

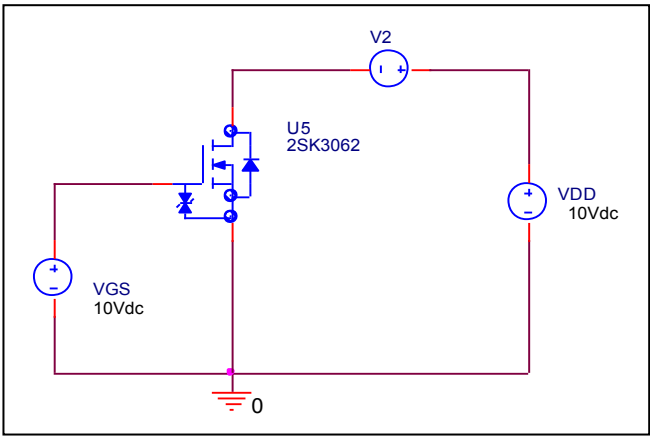
I_D (A)	V_{GS} (V)		Error (%)
	Measurement	Simulation	
0.1	1.850	1.827	-1.227
0.2	1.880	1.849	-1.665
0.5	1.925	1.891	-1.761
1	1.980	1.939	-2.071
2	2.040	2.007	-1.613
5	2.160	2.143	-0.773
10	2.315	2.298	-0.721
20	2.515	2.521	0.219
50	2.900	2.972	2.469

***Rds(on) Characteristic**

Circuit Simulation result



Evaluation circuit

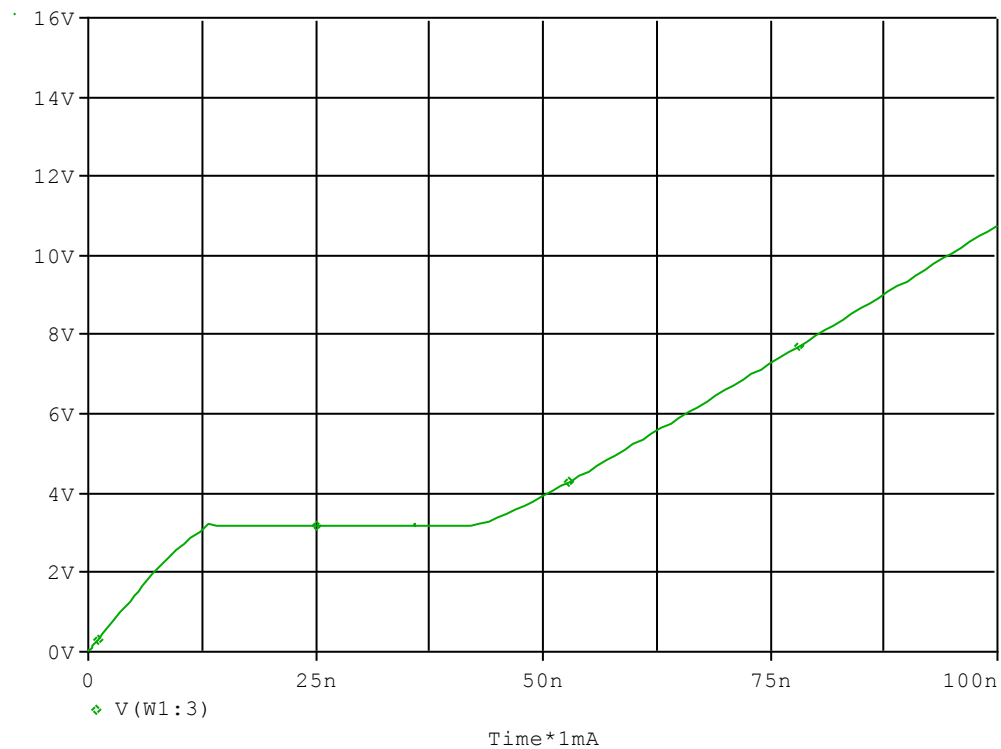


Simulation Result

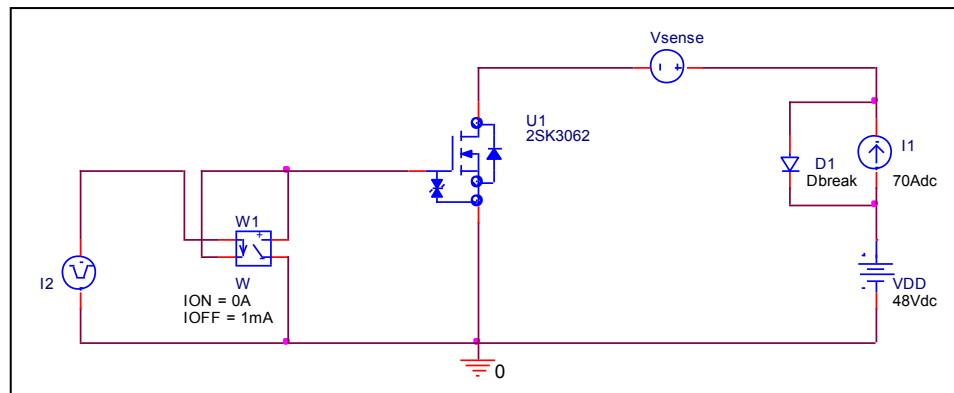
$I_D=35A, V_{GS}=10V$	Measurement		Simulation		Error (%)
$R_{DS} (on)$	6.30	mΩ	6.30	mΩ	0.00

Gate Charge Characteristic

Circuit Simulation result



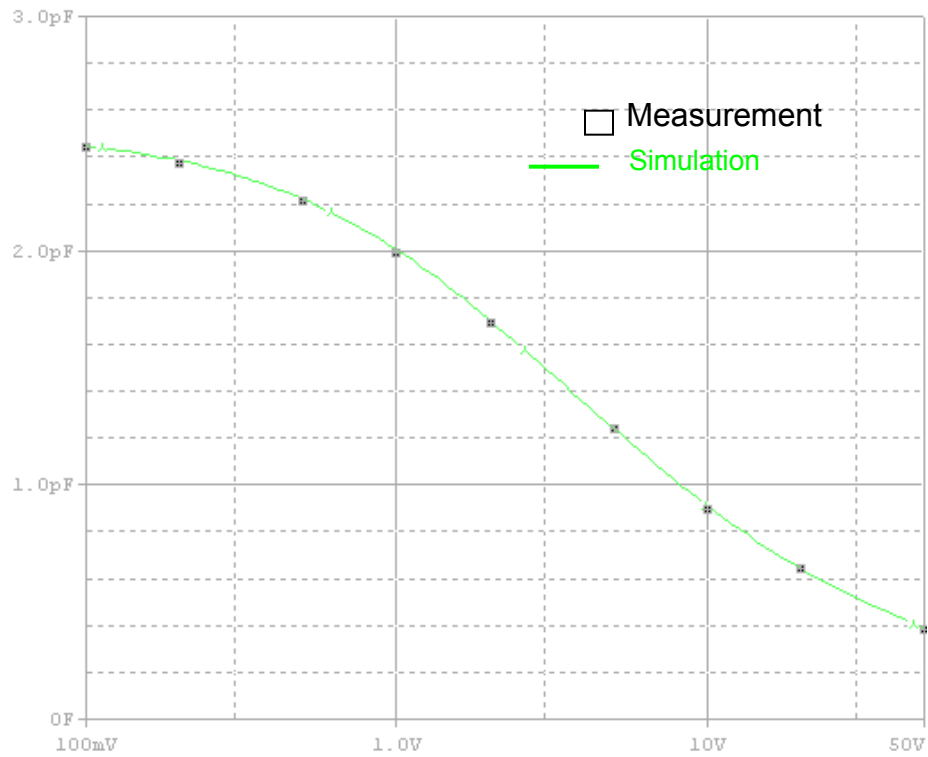
Evaluation circuit



Simulation Result

$V_{DD}=48V, I_D=70A$ $V_{GS}=10V$		Measurement	Simulation	Error (%)
Q_{gs}	nC	13.000	13.029	0.223
Q_{gd}	nC	30.000	29.993	-0.023
Q_g	nC	95.000	94.593	-0.428

Capacitance Characteristic

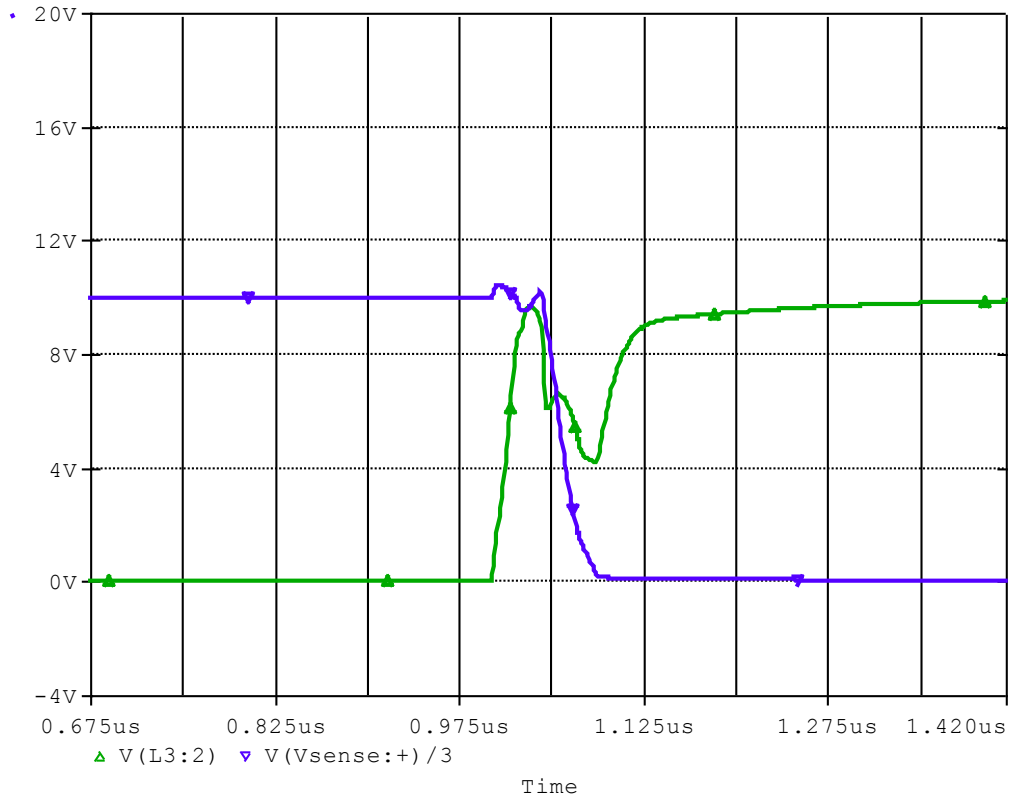


Simulation Result

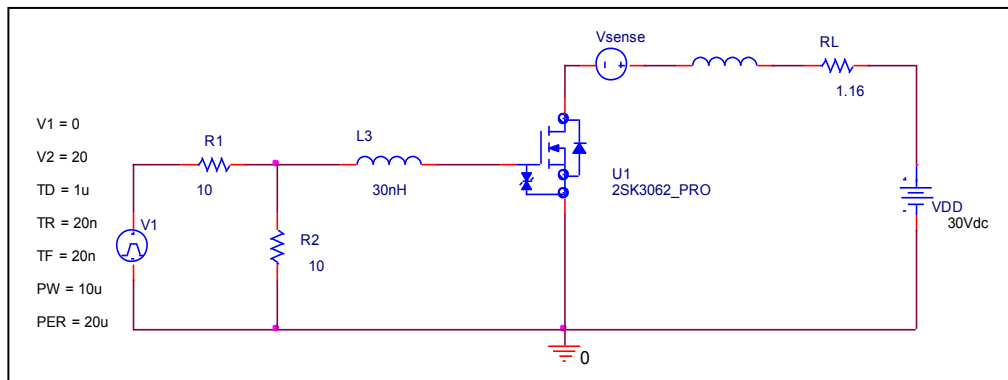
V_{DS} (V)	Cbd (pF)		Error(%)
	Measurement	Simulation	
0.1	2.450	2.430	-0.816
0.2	2.380	2.360	-0.840
0.5	2.220	2.240	0.901
1	2.000	1.980	-1.000
2	1.700	1.680	-1.176
5	1.250	1.230	-1.600
10	0.900	0.910	1.111
20	0.650	0.630	-3.077
50	0.390	0.400	2.564

Switching Time Characteristic

Circuit Simulation result



Evaluation circuit

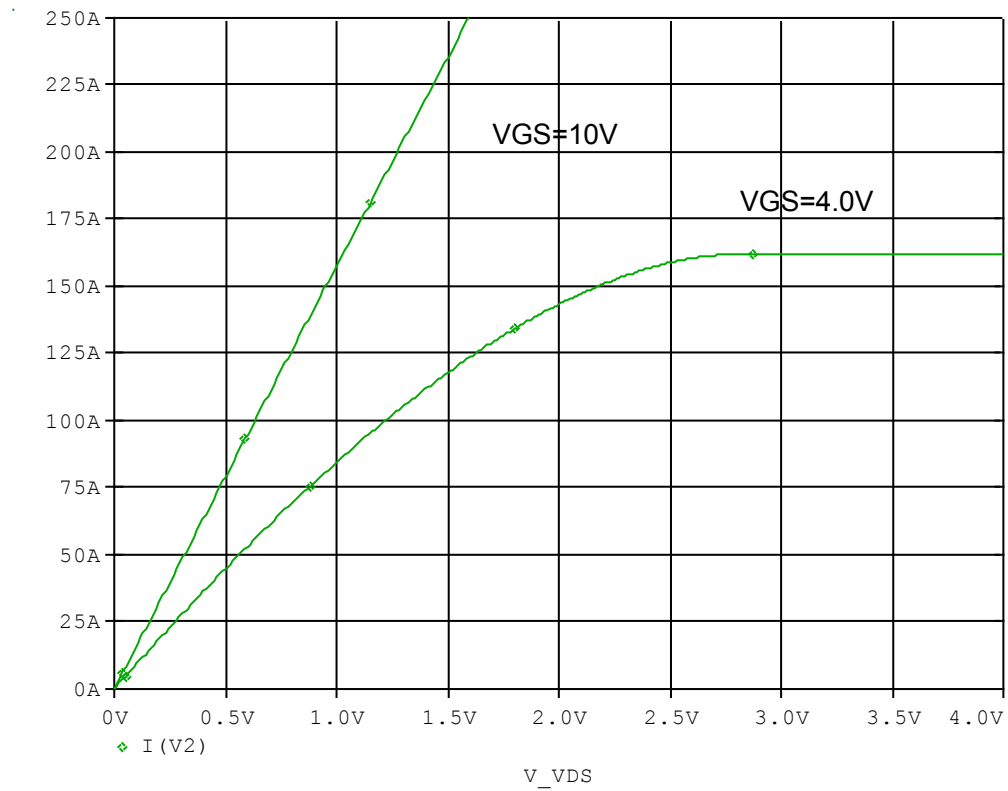


Simulation Result

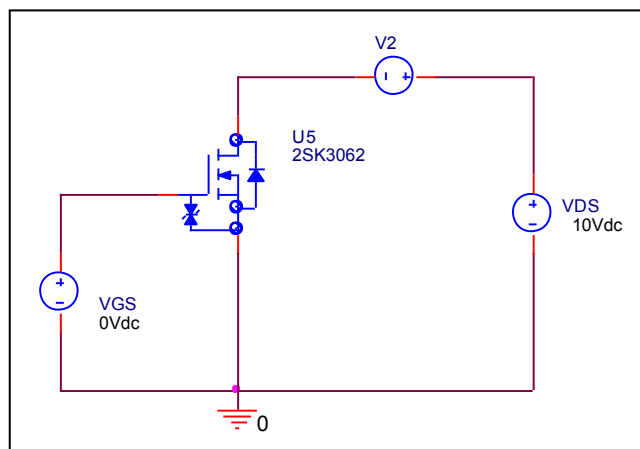
$I_D=35A$, $V_{DD}=30V$ $V_{GS}=0/10V$		Measurement	Simulation	Error(%)
t_d (on)	ns	75.00	84.91	-0.120

Output Characteristic

Circuit Simulation result



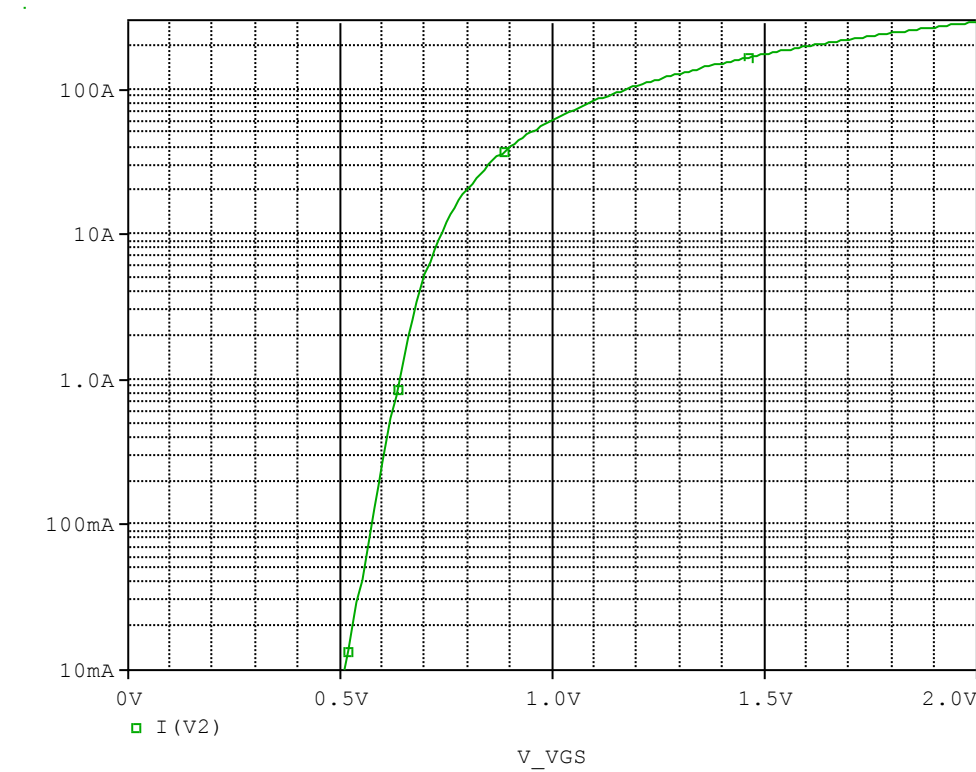
Evaluation circuit



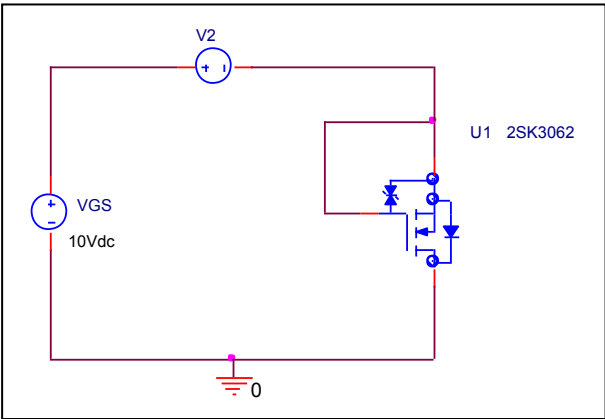
BODY DIODE SPICE MODEL

Forward Current Characteristic

Circuit Simulation Result

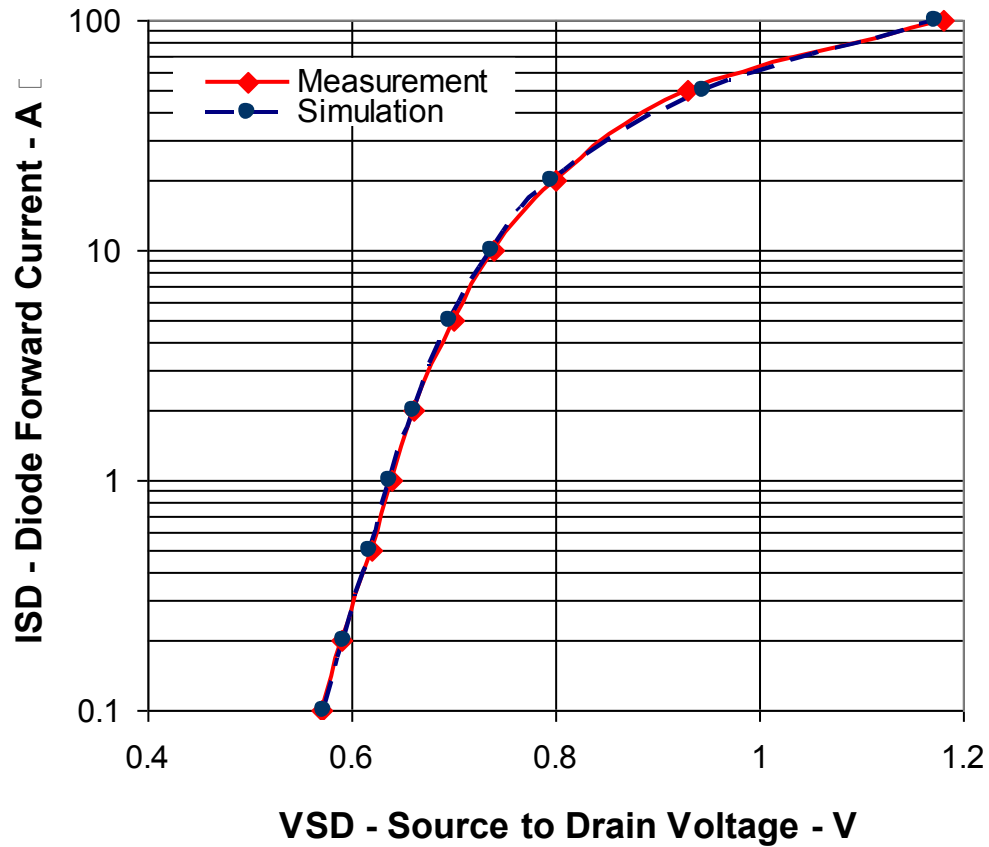


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

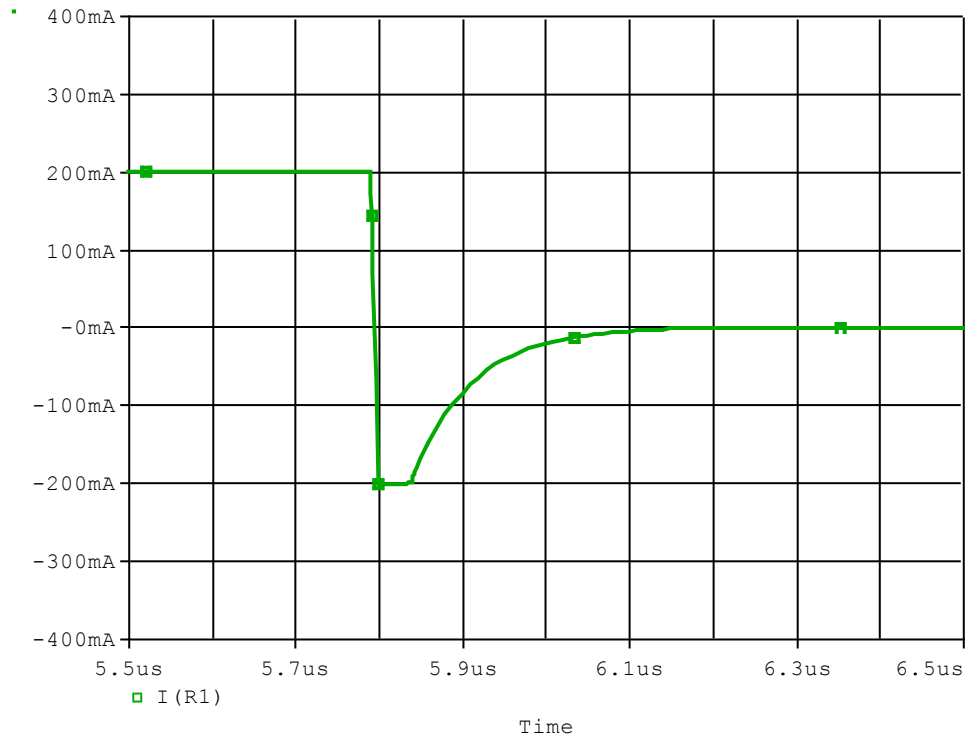


Simulation Result

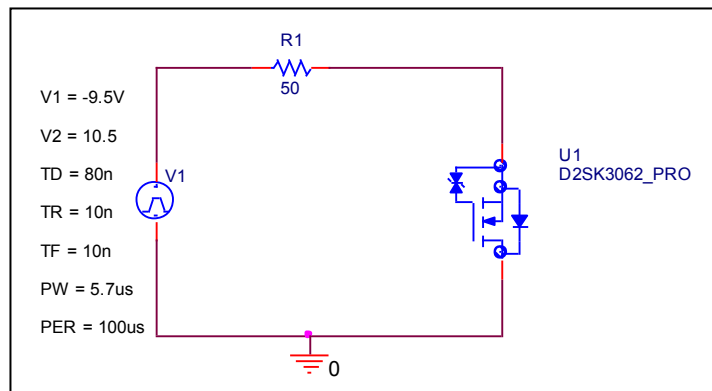
IDR(A)	VDS(V)		%Error
	Measurement	Simulation	
0.1	0.570	0.573	0.474
0.2	0.590	0.592	0.271
0.5	0.620	0.617	-0.484
1	0.640	0.638	-0.375
2	0.660	0.660	0.045
5	0.700	0.697	-0.429
10	0.740	0.736	-0.500
20	0.800	0.796	-0.450
50	0.930	0.946	1.720
100	1.180	1.173	-0.576

Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

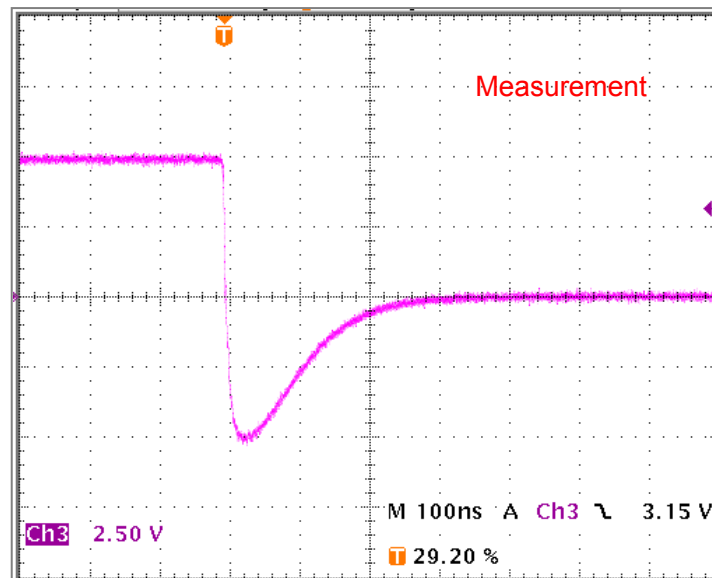


Compare Measurement vs. Simulation

		Measurement	Simulation	Error (%)
trj	ns	46.00	45.91	-0.20
trb	ns	162.00	161.53	-0.29
trr	ns	208.00	207.44	-0.27

Reverse Recovery Characteristic

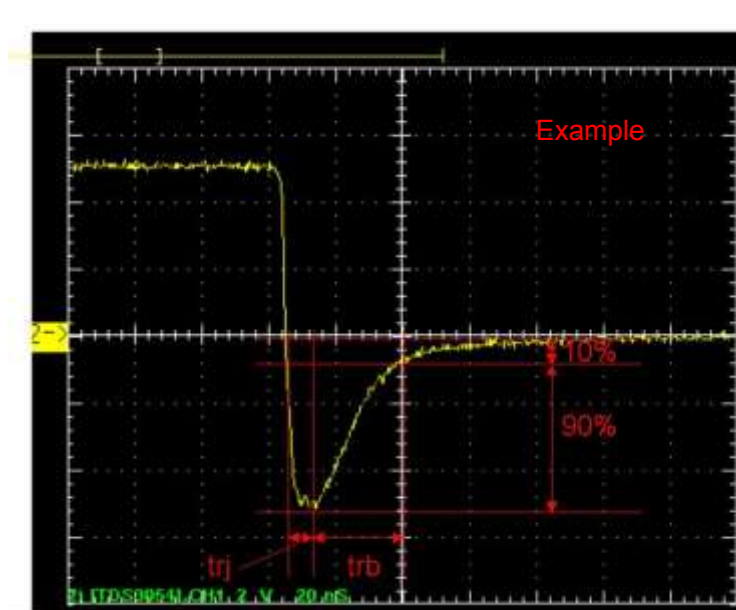
Reference



$T_{rr}=46.00(\text{ns})$

$T_{rb}=162.00(\text{ns})$

Conditions: $I_{fwd}=I_{rev}=0.2(\text{A})$, $R_L=50$

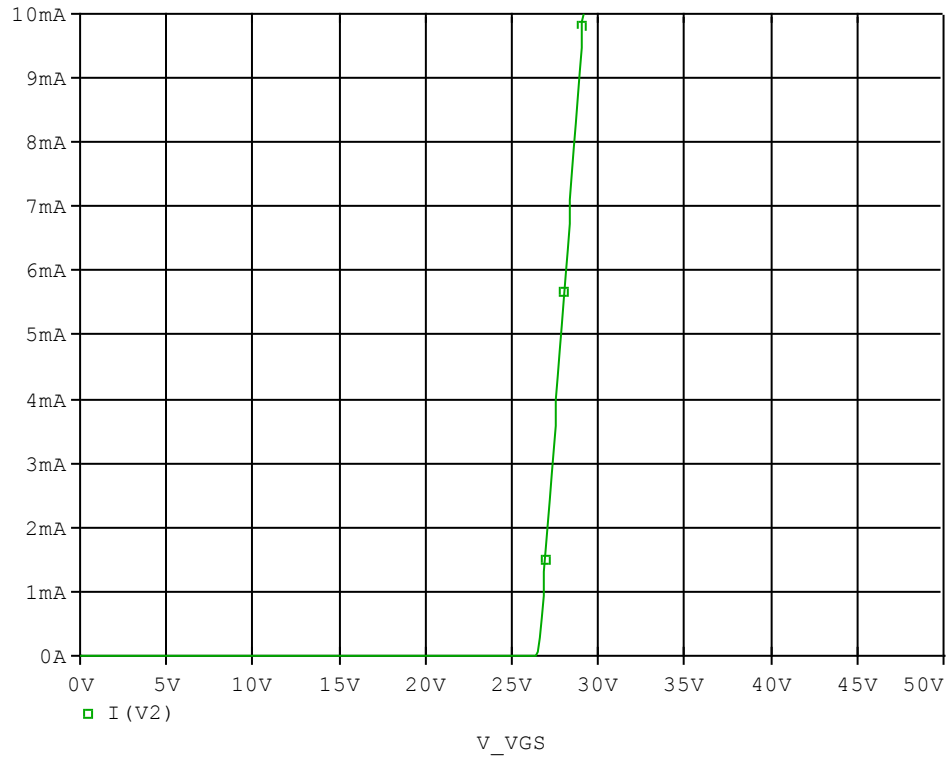


Relation between t_{rr} and t_{rb}

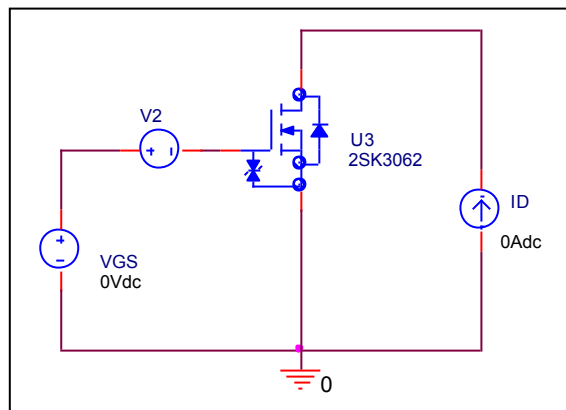
ESD PROTECTION DIODE SPICE MODEL

Zener Voltage Characteristic

Circuit Simulation Result



Evaluation Circuit



Zener Voltage Characteristic

Reference

